Electronic Supplementary Information (ESI)

## Single Atom Doped Arsenene as Elecocatalysts for Reducing Nitrogen to Ammonia: A DFT Study

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Metal (m)	$d_{m-As}(\mathbf{\hat{A}})$
V	2.47
Cr	2.46
Fe	2.39
Со	2.27
Cu	2.37
Ru	2.36
Pd	2.44
Ag	2.54
Pt	2.41
Au	2.49

 Table S1 The average bond lengths of metal-As.

 Table S2 The band gap values (DFT-PBE level) of TM doped arsenene.

TM/Ars	Band gap value (eV)
V/Ars	~ 0.00
Cr/Ars	0.78
Fe/Ars	~ 0.00
Co/Ars	0.66
Cu/Ars	~ 0.00
Ru/Ars	0.25
Pd/Ars	~ 0.00
Ag/Ars	~ 0.00
Pt/Ars	~ 0.00
Au/Ars	$\sim 0.00$

Metal (m)	$d_{N-N}(\text{\AA})$	$Q_{system-N_2}$ (e)
V	1.13	0.32
Cr	1.12	0.21
Fe	1.14	0.35
Со	1.13	0.20
Ru	1.13	0.28

Table S3 The Gibbs free energies change of  $N_2$  adsorption with the most favorable manner, and the distant of N-N bond. Bader charge for TM-doped system and  $N_2$  molecule.

**Table S4** The comparable results of this work and the others NRR catalysts.

Catalysts	U <sub>oneset</sub> (V)	Refs.
V/Ars	-0.26	In this work
<b>B-B</b> <sub>1</sub> <b>P</b> and <b>B-B</b> <sub>b</sub> <b>P</b>	-0.78 and -0.92	1
Ru/ Boron	-0.42	2
Ru <sub>1</sub> @C <sub>2</sub> N, Ru <sub>1</sub> @T-C <sub>3</sub> N <sub>4</sub> , and Ru <sub>1</sub> @γ-graphynes	-0.94, -0.96 and -0.98	3
W@g-C <sub>3</sub> N <sub>4</sub>	-0.35	4
Mo@C <sub>2</sub> N	-0.17	5
V@β <sub>12</sub> -Boron	-0.28	6
B/g-C <sub>3</sub> N <sub>4</sub>	-0.20	7



**Fig. S1** The pristine arsenene nanosheet of (a) top view and side view, and (b) the corresponding band structure (DFT-PBE level). The Fermi-level is set to be zero denoted by dash line. The green color is represented for arsenic atom.



**Fig. S2** Electronic band structures (DFT-PBE level) of TM atoms (i.e., V, Cr, Fe, Co, Cu, Ru, Pd, Ag, Pt and Au) doped arsenene. The Fermi-level is indicated by the dash line, and red and blue spots represents TM contributions from majority and minority spins.



Fig. S3 The N<sub>2</sub> adsorption on TM/Ars with end-on and side-on configurations.



**Fig. S4** Free energies profiles for Fe-, Co-, Ru-doped arsenene nanosheet via distal ways (i.e., (a) (c) (e)) and alternating ways (i.e., (b) (d) (f)).



**Fig. S5** The variation of the N=N bond length  $(d_{N-N})$  via the enzymatic pathway on V/Ars electrocatalyst for NRR process.

## Reference

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